SCS210AM

SiC Schottky Barrier Diode

Datasheet

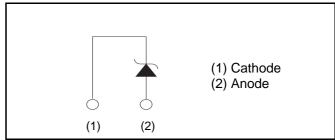
V_R	650V
I _F	10A
Q_{C}	15nC

Outline TO-220FM

Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

●Inner circuit



Applications

- PFC Boost Topology
- Secondary Side Rectification
- Data Center
- PV Power Conditioners

●Packaging specifications

or dokaging specifications				
	Packaging	Tube		
	Reel size (mm)	-		
Typo	Tape width (mm)	-		
Туре	Basic ordering unit (pcs)	50		
	Packing code	С		
	Marking	SCS210AM		

● Absolute maximum ratings (T_i = 25°C)

Parameter		Symbol	Value	Unit
Reverse voltage (repetitive peak)		V_{RM}	650	V
Reverse voltage (D	C)	V_R	650	V
Continuous forward	current (T _c = 85°C)	I _F	10	А
Surge non-			38	А
repetitive forward	PW=10ms sinusoidal, T _j =150°C	I _{FSM}	30	А
current	PW=10μs square, T _j =25°C		150	А
Repetitive peak forward current		I _{FRM}	28 ^{*1}	А
PW=10ms, T _j =25°C		۲۰۶۰	7.2	A ² s
i ² t value	PW=10ms, T _j =150°C	$\int i^2 dt$	4.5	A ² s
Total power dissipation		P_{D}	34 *2	W
Junction temperature		T _j	175	°C
Range of storage temperature		T_{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

●Electrical characteristics (T_j = 25°C)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =2.0mA	650	-	-	V
	V _F	I _F =10A,T _j =25°C	-	1.35	1.55	V
Forward voltage		I _F =10A,T _j =150°C	-	1.55	-	V
		I _F =10A,T _j =175°C	-	1.63	-	V
Reverse current	I _R	V _R =650V,T _j =25°C	-	2	200	μΑ
		V _R =650V,T _j =150°C	-	30	-	μΑ
		V _R =650V,T _j =175°C	-	70	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	360	-	pF
		V _R =600V,f=1MHz	-	37	-	pF
Total capacitive charge	Q _C	V _R =400V,di/dt=350A/μs	-	15	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	-	15	-	ns

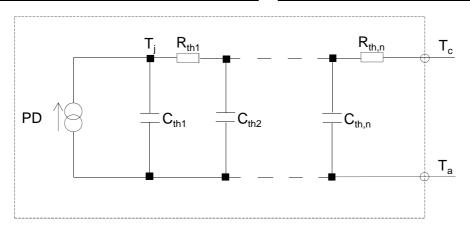
●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	R _{th(j-c)}	-	-	3.6	4.3	°C/W

● Typical Transient Thermal Characteristics

Symbol	Value	Unit
R _{th1}	7.04E-01	
R _{th2}	1.29E+00	K/W
R _{th3}	1.62E+00	

Symbol	Value	Unit
C_{th1}	1.89E-03	
C_{th2}	8.38E-03	Ws/K
C_{th3}	7.07E-01	



Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

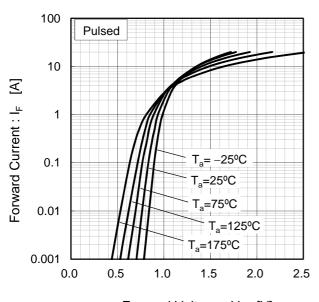
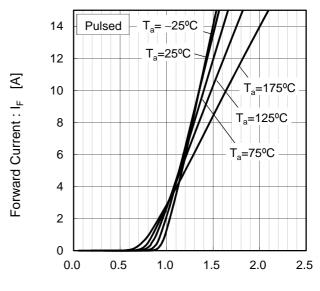


Fig.2 V_F - I_F Characteristics



Forward Voltage : V_F [V]

Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics

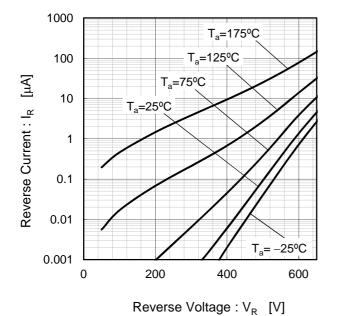
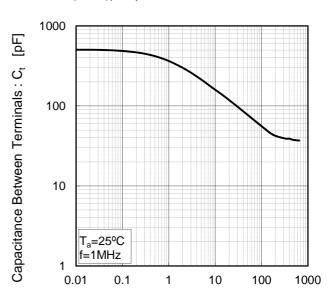


Fig.4 V_R - C_t Characteristics



Reverse Voltage : V_R [V]

Electrical characteristic curves

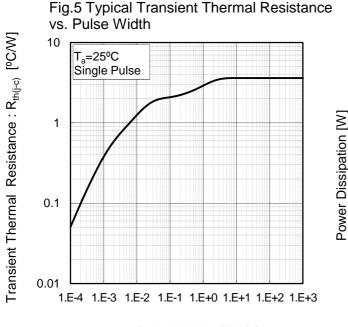
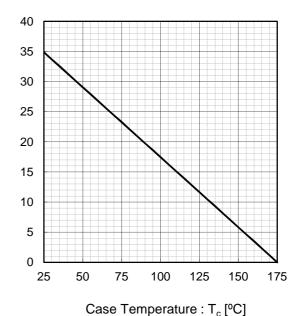


Fig.6 Power Dissipation



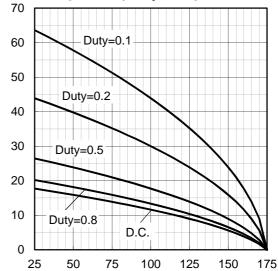
Pulse Width: PW [s]

Fig.7*3 Maximum peak forward current derating curve I_P - T_c 70 60

Peak Forward Current : IP [A] 50 Duty=0.1 40 Duty=0.2 30 Duty=0.5 20 10 Duty=0.8 D.C. 0 100 25 50 75 125 150 175

Case Temperature : T_c [°C] *3 Based on max Vf, max R_{th(j-c)} Valid for switching of above 10kHz, excluding D.C. curve.

Fig.8*4 Typical peak forward current derating curve I_P - T_c (Not guaranteed)

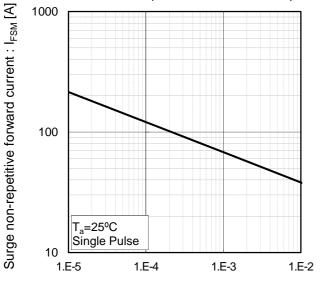


Case Temperature : T_c [°C] *4 Based on typ Vf, typ R_{th(j-c)} Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

Peak Forward Current : I_P [A]

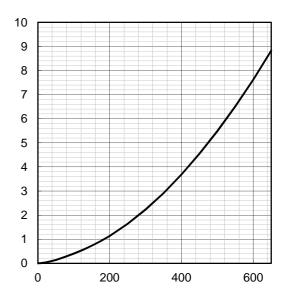
•Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



Pulse Width: PW [s]

Fig.10 Typical capacitance store energy

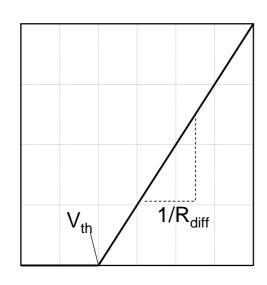


Capacitance stored energy : $\mathsf{E}_{_{\mathrm{C}}}[\mu \mathsf{J}]$

Reverse Voltage : V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage: V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$\begin{aligned} &V_{th}\left(\ T_{j}\ \right) = a_{0} + a_{1} \, T_{j} \\ &R_{diff}\left(\ T_{j}\ \right) = b_{0} + b_{1} \, T_{j} + b_{2} \, T_{j}^{2} \end{aligned}$$

Symbol	Typical Value	Unit
a ₀	9.35E-01	V
a ₁	-1.12E-03	V/°C
b ₀	3.98E-02	Ω
b ₁	1.02E-04	Ω/°C
b ₂	1.08E-06	$\Omega/^{\circ}C^{2}$

 T_i in °C; -55 °C < T_i < °C; I_F < 20 A

Forward Current: IF

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